

PATENT APPLICATION

Docket No.: 4591-306

Serial No. not yet assigned

Applicant: Jae-Yoon Sim

Filing Date: June 30, 2003

Group: not yet assigned

INFORMATION DISCLOSURE CITATION  
FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

<u>Exam</u>	<u>Init</u>	<u>Ref</u>	<u>Document Number</u>	<u>Issue Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub Class</u>

FOREIGN PATENT DOCUMENTS

<u>Exam</u>	<u>Init</u>	<u>Ref</u>	<u>Document Number</u>	<u>Publication Date</u>	<u>Country</u>	<u>Name</u>

OTHER DOCUMENTS

<u>Exam</u>	<u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>

Article from IEEE Journal of Solid-State Circuits, Vol. 29 No. 1, pp. 9-13  
January 1994, entitled "OFFSET COMPENSATING BIT-LINE SENSING  
SCHEME FOR HIGH DENSITY DRAM'S"

Examiner: M. TRAN

Date Considered: 6/22/04